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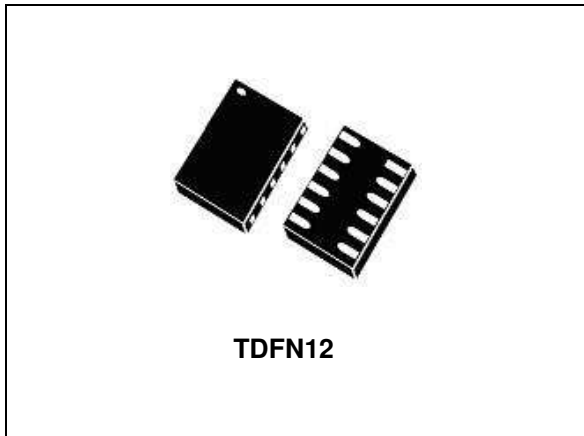
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Smart push-button on/off controller with Smart Reset™ and power-on lockout

Datasheet - production data



- Industrial operating temperature -40 to +85 °C
- Available in TDFN12 2 x 3 mm package

Applications

- Wearable
- Activity tracker
- Smartwatch
- Smartglasses

Features

- Operating voltage 1.6 V to 5.5 V
- Low standby current of 0.6 μ A
- Adjustable Smart Reset™ assertion delay time driven by external C_{SRD}
- Power-up duration determined primarily by push-button press
- Debounced \overline{PB} and \overline{SR} inputs
- \overline{PB} and \overline{SR} ESD inputs withstand voltage up to ± 15 kV (air discharge) ± 8 kV (contact discharge)
- Active high or active low enable output option (\overline{EN} or \overline{EN}) provides control of MOSFET, DC-DC converter, regulator, etc.
- Secure startup, interrupt, Smart Reset™ or power-down driven by push-button
- Precise 1.5 V voltage reference with 1% accuracy

Table 1. Device summary

Device	\overline{RST}	C_{SRD}	$\overline{PB} / \overline{SR}$	\overline{EN} or \overline{EN}	\overline{INT}	Startup process
SRC0	open drain ⁽¹⁾	3	3	push-pull	open drain ⁽¹⁾	\overline{PB} must be held low until the PS_{HOLD} ⁽²⁾ confirmation

1. External pull-up resistor needs to be connected to open drain outputs.

2. For a successful startup, the PS_{HOLD} (Power Supply Hold) needs to be pulled high within specific time, t_{ON_BLANK} .

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1 Description

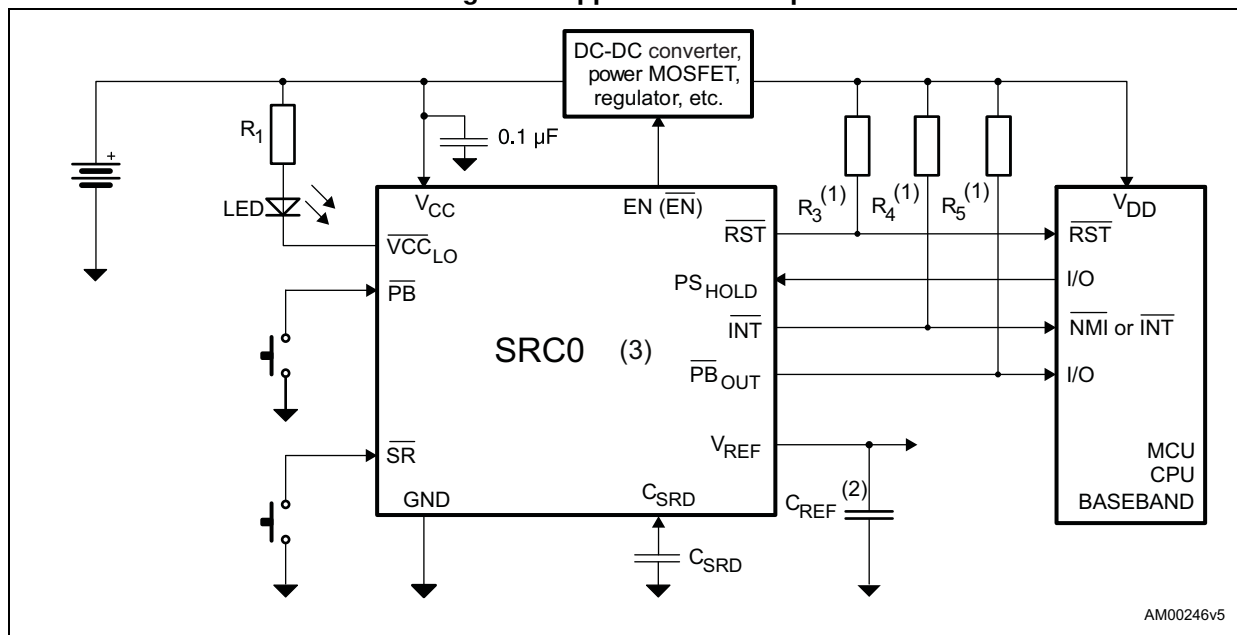
The SRC0 devices monitor the state of connected push-button(s) as well as sufficient supply voltage. An enable output controls power for the application through the MOSFET transistor, DC-DC converter, regulator, etc. If the supply voltage is above a precise voltage threshold, the enable output can be asserted by a simple press of the button. Factory-selectable supply voltage thresholds are determined by highly accurate and temperature-compensated references. An interrupt is asserted by pressing the push-button during normal operation and can be used to request a system power-down. The interrupt is also asserted if undervoltage is detected. By a long push of one button (\overline{PB}) or two buttons (\overline{PB} and \overline{SR}) either a reset is asserted or power for the application is disabled depending on the option used.

The device also offers additional features such as precise 1.5 V voltage reference with very tight accuracy of 1%, separate output indicating undervoltage detection and separate output for distinguishing between interrupt by push-button or undervoltage.

The device consumes very low current of 6 μA during normal operation and only 0.6 μA current during standby.

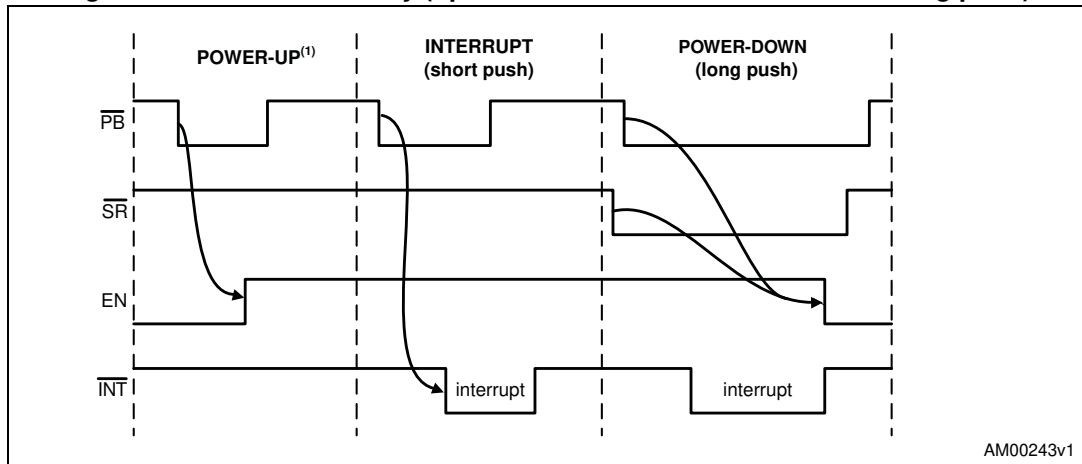
The SRC0 is available in the TDFN12 package and is offered in several options among features such as selectable threshold, hysteresis, timeouts, output types, etc.

Figure 1. Application hookup



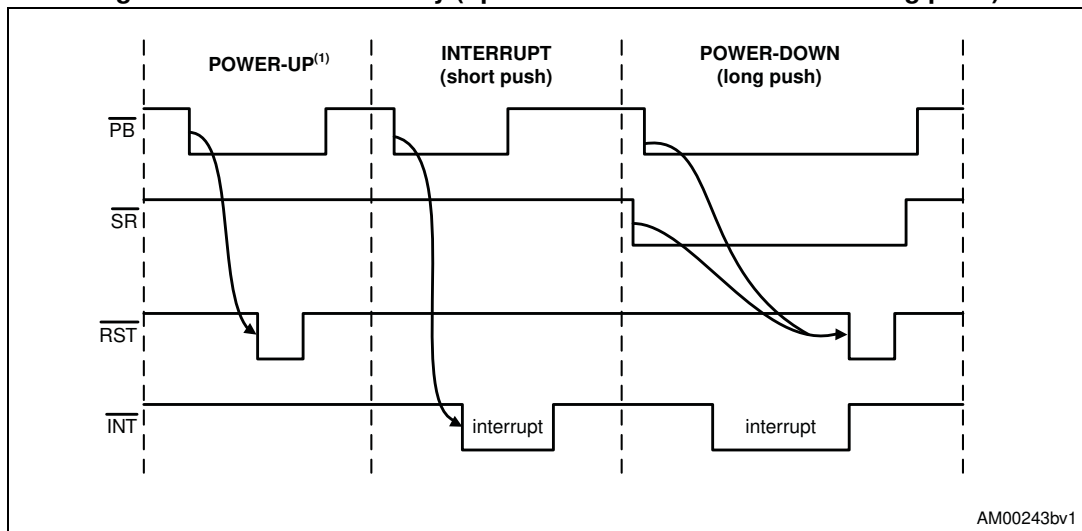
1. A resistor is required for open drain output type only. A 10 k Ω pull-up is sufficient in most applications.
2. Capacitor C_{REF} is mandatory on V_{REF} output (even if V_{REF} is not used). Capacitor value of 1 μF is recommended.
3. For the SRC0 the processor has to confirm the proper power-on during the fixed time period, t_{ON_BLANK} . This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.

Figure 2. Basic functionality (option with enable deassertion after long push)



1. For power-up the battery voltage has to be above V_{TH+} threshold.

Figure 3. Basic functionality (option with \overline{RST} assertion after long push)



1. For power-up the battery voltage has to be above V_{TH+} threshold.

Figure 4. Logic diagram

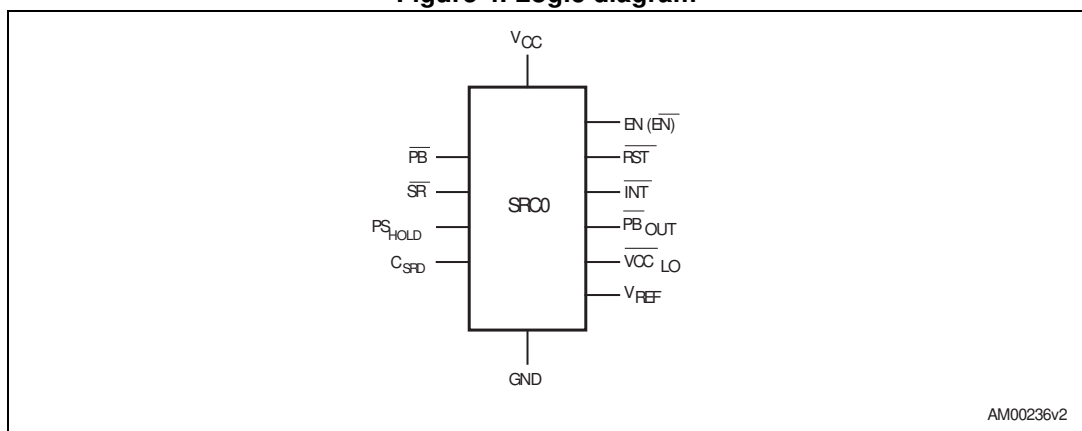


Table 2. Pin descriptions

Pin n°	Symbol	Function
1	V_{CC}	Power supply input
2	\overline{SR}	Smart Reset™ button input
3	V_{REF}	Precise 1.5 V voltage reference
4	PS_{HOLD}	PS_{HOLD} input
5	C_{SRD}	Adjustable Smart Reset™ delay time input
6	\overline{PB}	Push-button input
7	\overline{VCC}_{LO}	Output for high threshold comparator output (V_{TH+})
8	PB_{OUT}	Status of \overline{PB} push-button input
9	EN or \overline{EN}	Enable output
10	RST	Reset output
11	INT	Interrupt output
12	GND	Ground

Figure 5. TDFN12 pin connections

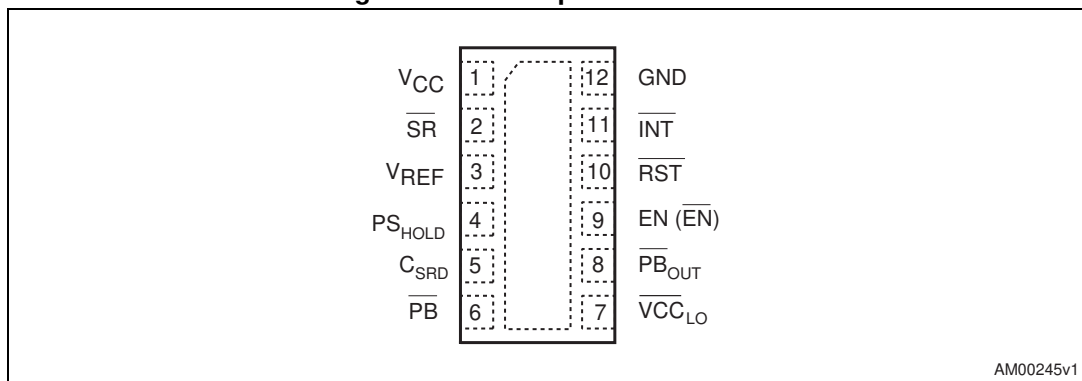
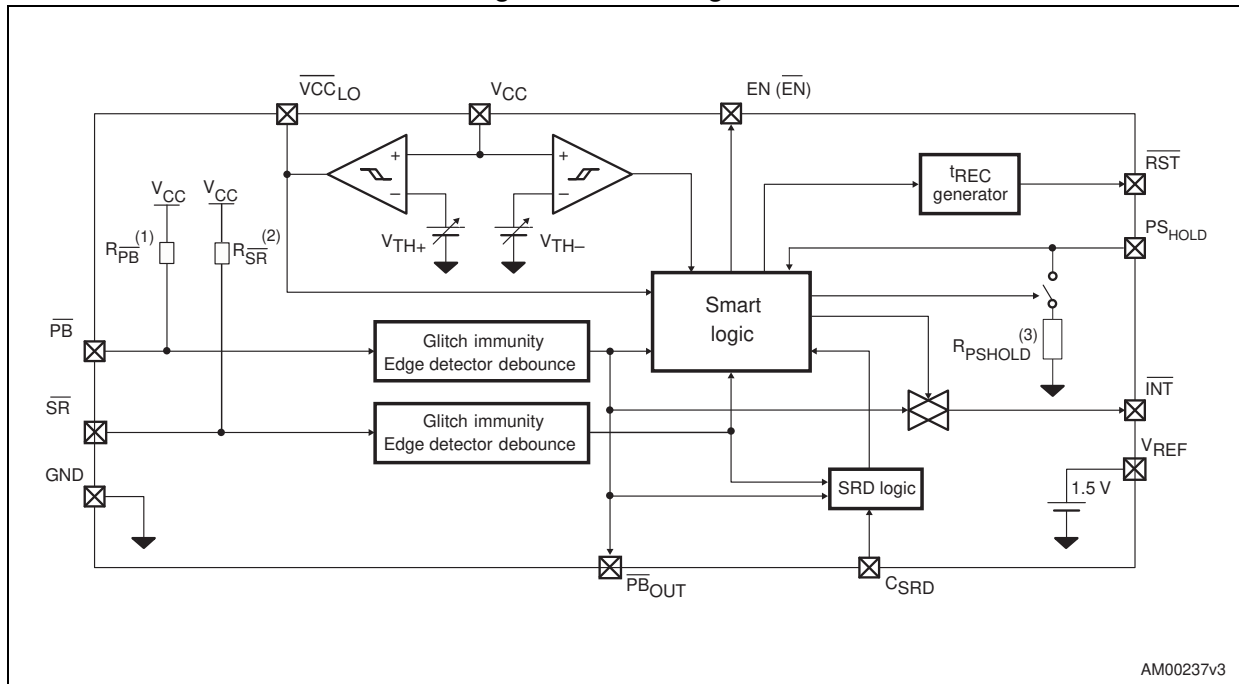


Figure 6. Block diagram



AM00237v3

1. Internal pull-up resistor connected to \overline{PB} input (see [Table 5](#) for precise specifications).
2. Optional internal pull-up resistor connected to \overline{SR} input (see [Table 5](#) for precise specifications).
3. Internal pull-down resistor is connected to PS_{HOLD} input only during startup (see [Figure 7](#), [8](#), [9](#), [10](#), [11](#), [12](#), [13](#), and [18](#)).

2 Pin descriptions

V_{CC} - power supply input

V_{CC} is monitored during startup and normal operation for sufficient voltage level. Decouple the V_{CC} pin from ground by placing a 0.1 μF capacitor as close to the device as possible.

$\overline{\text{SR}}$ - Smart Reset™ button input

This input is equipped with voltage detector with a factory-trimmed threshold and has ± 8 kV HBM ESD protection.

Both $\overline{\text{PB}}$ and $\overline{\text{SR}}$ buttons have to be pressed and held for t_{SRD} period so the long push is recognized and the reset is asserted (or the enable output is deasserted depending on the option) - see [Figure 13](#), [14](#), and [15](#).

Active low $\overline{\text{SR}}$ input is usually connected to GND through the momentary push-button (see [Figure 1](#)) and it has an optional 100 k Ω pull-up resistor. It is also possible to drive this input using an external device with either open drain (recommended) or push-pull output. Open drain output can be connected in parallel with push-button or other open drain outputs, which is not possible with push-pull output. $\overline{\text{SR}}$ input is monitored for falling edge after power-up and must not be grounded permanently.

V_{REF} - external precise 1.5 V voltage reference

This 1.5 V voltage reference is specified with very tight accuracy of 1% (see [Table 5](#)). It has proper output voltage as soon as the reset output is deasserted (i.e. after t_{REC} expires) and it is disabled when the device enters standby mode. A mandatory capacitor needs to be connected to V_{REF} output (even if V_{REF} is not used). Capacitor value of 1 μF is recommended.

PS_{HOLD} input

This input is equipped with a voltage detector with a factory-trimmed threshold. It is used to confirm correct power-up of the device (if EN or $\overline{\text{EN}}$ is not asserted) or to initiate a shutdown (if EN or $\overline{\text{EN}}$ is asserted).

Forcing PS_{HOLD} high during power-up confirms the proper start of the application and keeps enable output asserted. Because most processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS_{HOLD} input during startup (see [Figure 7](#), [8](#), [9](#), [10](#), [11](#), [12](#), [13](#), and [18](#)).

Forcing the PS_{HOLD} signal low during normal operation deasserts the enable output (see [Figure 12](#)). Input voltage on this pin is compared to an accurate voltage reference.

C_{SRD} - Smart Reset™ delay time input

A capacitor to ground determines the additional time (t_{SRD}) that $\overline{\text{PB}}$ with $\overline{\text{SR}}$ must be pressed and held before a long push is recognized. The connected C_{SRD} capacitor is charged with I_{SRD} current. Additional Smart Reset™ delay time t_{SRD} ends when voltage on the C_{SRD} capacitor reaches the V_{SRD} voltage threshold. It is recommended to use a low ESR capacitor (e.g. ceramic). If the capacitor is not used, leave the C_{SRD} pin open. If no capacitor is connected, there is no t_{SRD} and a long push is recognized right after $t_{\text{INT_Min}}$ expires (see [Figure 18](#) and [19](#)).

$\overline{\text{PB}}$ - power ON switch

This input is equipped with a voltage detector with a factory-trimmed threshold and has ± 8 kV HBM ESD protection.

When the $\overline{\text{PB}}$ button is pressed and held, the battery voltage is detected and EN (or $\overline{\text{EN}}$) is asserted if the battery voltage is above the threshold $V_{\text{TH}+}$ during the whole t_{DEBOUNCE} period (see [Figure 13](#)).

A short push of the push-button during normal operation can initiate an interrupt through debounced INT output (see [Figure 14](#)) and a long push of $\overline{\text{PB}}$ and SR simultaneously can either assert reset output RST (see [Figure 18](#)) or deassert the EN or $\overline{\text{EN}}$ output (see [Figure 19](#)) based on the option used.

Note: A switch to GND must be connected to this input (e.g. mechanical push-button, open drain output of external circuitry, etc.), see [Figure 1](#). This ensures a proper startup signal on $\overline{\text{PB}}$ (i.e. a transition from full V_{CC} below specified V_{IL}). $\overline{\text{PB}}$ input has an internal 100 k Ω pull-up resistor connected.

$\overline{\text{VCC}}_{\text{LO}}$ - high threshold detection output

During power-up, $\overline{\text{VCC}}_{\text{LO}}$ is low when V_{CC} supply voltage is below the $V_{\text{TH}+}$ threshold. After successful power-up (i.e. during normal operation) $\overline{\text{VCC}}_{\text{LO}}$ is low anytime undervoltage is detected (see [Figure 13](#)).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

$\overline{\text{VCC}}_{\text{LO}}$ is floating when SRC0 is in standby mode.

$\overline{\text{PB}}_{\text{OUT}}$ - $\overline{\text{PB}}$ input state

If the push-button $\overline{\text{PB}}$ is pressed, the pin stays low during the t_{DEBOUNCE} time period. If $\overline{\text{PB}}$ is asserted for the entire t_{DEBOUNCE} period, $\overline{\text{PB}}_{\text{OUT}}$ will then stay low for at least $t_{\text{INT_Min}}$. If $\overline{\text{PB}}$ is asserted after $t_{\text{INT_Min}}$ expires, $\overline{\text{PB}}_{\text{OUT}}$ will return high as soon as $\overline{\text{PB}}$ is deasserted (see [Figure 22](#)). $\overline{\text{PB}}_{\text{OUT}}$ ignores $\overline{\text{PB}}$ assertion during an undervoltage condition. At startup on the SRC0 $\overline{\text{PB}}_{\text{OUT}}$ will respond only to the first $\overline{\text{PB}}$ assertion and any other assertion will be ignored until $t_{\text{ON_BLANK}}$ expires. This output is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

EN or $\overline{\text{EN}}$ - enable output

This output is intended to enable system power (see [Figure 1](#)). EN is asserted **high** after a valid turn-on event has been detected and confirmed (i.e. push-button has been pressed and held for t_{DEBOUNCE} or more and $V_{\text{CC}} > V_{\text{TH+}}$ voltage level has been detected - see [Figure 13](#)). EN is released **low** if any of the conditions below occur:

- the push-button is released before PS_{HOLD} is driven high.
- PS_{HOLD} is driven low during normal operation (see [Figure 14](#)).
- an undervoltage condition is detected for more than $t_{\text{SRD}} + t_{\text{INT_Min}} + t_{\text{DEBOUNCE}}$ (see [Figure 21](#)).
- a long push of the buttons is detected (only for the device with option “EN deasserted by long push” - see [Figure 19](#)) or PS_{HOLD} is not driven high during $t_{\text{ON_BLANK}}$ after a long push of the buttons (only for the device with option “RST asserted by long push” - see [Figure 18](#)).

Described logic levels are inverted in case of $\overline{\text{EN}}$ output. Output type is push-pull by default.

$\overline{\text{RST}}$ - reset output

This output pulls low for t_{REC} :

- during startup. $\overline{\text{PB}}$ has been pressed (falling edge on the $\overline{\text{PB}}$ detected) and held for at least t_{DEBOUNCE} and $V_{\text{CC}} > V_{\text{TH+}}$ (see [Figure 7, 8, 9, 10, 11, 12](#) and [13](#) for more details).
- after long push detection (valid only for the device with option “ $\overline{\text{RST}}$ asserted by long push”). $\overline{\text{PB}}$ has been pressed (falling edge on the $\overline{\text{PB}}$ detected) and held for more than $t_{\text{DEBOUNCE}} + t_{\text{SRD}}$ (additional Smart Reset™ delay time can be adjusted by the external capacitor C_{SRD}) - see [Figure 18](#).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

$\overline{\text{INT}}$ - interrupt output

While the system is under normal operation (PS_{HOLD} is driven high, power for application is asserted), the $\overline{\text{INT}}$ is driven **low** if:

- V_{CC} falls below $V_{\text{TH-}}$ threshold (i.e. undervoltage is detected - see [Figure 20](#) and [21](#)).
- the falling edge on the $\overline{\text{PB}}$ is detected and the push-button is held for t_{DEBOUNCE} or more. $\overline{\text{INT}}$ is driven low after t_{DEBOUNCE} and stays low as long as $\overline{\text{PB}}$ is held. The $\overline{\text{INT}}$ signal is held high during power-up.

The state of the $\overline{\text{PB}}_{\text{OUT}}$ output can be used to determine if the interrupt was caused by either the assertion of the $\overline{\text{PB}}$ input, or was due to the detection of an undervoltage condition on V_{CC} .

$\overline{\text{INT}}$ output is asserted low for at least $t_{\text{INT_Min}}$.

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

GND - ground

3 Operation

The SRC0 simplified smart push-button on/off controller with Smart Reset™ and power-on lockout enables and disables power for the application depending on push-button states, signals from the processor, and battery voltage.

Power-on

Because most of the processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS_{HOLD} input during startup (see [Figure 7, 8, 9, 10, 11, 12, 13, and 18](#)).

To power up the device the push-button $\overline{\text{PB}}$ has to be pressed for at least t_{DEBOUNCE} and V_{CC} has to be above $V_{\text{TH+}}$ for the whole t_{DEBOUNCE} period. If the battery voltage drops below $V_{\text{TH+}}$ during the t_{DEBOUNCE} , the counter is reset and starts to count again when $V_{\text{CC}} > V_{\text{TH+}}$ (see [Figure 13](#)). After t_{DEBOUNCE} the enable signal is asserted (EN goes high, $\overline{\text{EN}}$ goes low), reset output $\overline{\text{RST}}$ is asserted for t_{REC} and then the startup routine is performed by the processor. During initialization, the processor sets the PS_{HOLD} signal high.

On the SRC0 the PS_{HOLD} signal has to be set high prior to push-button release and $t_{\text{ON_BLANK}}$ expiration, otherwise the enable signal is deasserted (EN goes low, $\overline{\text{EN}}$ goes high) - see [Figure 7, 8, 9, and 10](#). The time up to push-button release represents the maximum time allowed for the system to power up and initialize the circuits driving the PS_{HOLD} input. If the PS_{HOLD} signal is low at push-button release, the enable output is deasserted immediately, thus turning off the system power. If $t_{\text{ON_BLANK}}$ expires prior to push-button release, the PS_{HOLD} state is checked at its expiration. This safety feature disables the power and prevents discharging the battery if the push-button is stuck or it is held for an unreasonable period of time and the application is not responding (see [Figure 8 and 10](#)). $\overline{\text{PB}}$ status, $\overline{\text{INT}}$ status and V_{CC} undervoltage detection are not monitored until power-up is completed.

Push-button interrupt

If the device works under normal operation (i.e. PS_{HOLD} is high) and the push-button $\overline{\text{PB}}$ is pressed for more than t_{DEBOUNCE} , a negative pulse with minimum $t_{\overline{\text{INT}}_{\text{Min}}}$ width is generated on the $\overline{\text{INT}}$ output. By connecting $\overline{\text{INT}}$ to the processor interrupt input (INT or NMI) a safeguard routine can be performed and the power can be shut down by setting PS_{HOLD} low - see [Figure 14](#).

Forced power-down mode

The PS_{HOLD} output can be forced low anytime during normal operation by the processor and can deassert the enable signal - see [Figure 14](#).

Undervoltage detection

If V_{CC} voltage drops below $V_{\text{TH-}}$ voltage threshold during normal operation, the $\overline{\text{INT}}$ output is driven low (see [Figure 20 and Figure 21](#)).

If an undervoltage condition is detected for $t_{\text{DEBOUNCE}} + t_{\overline{\text{INT}}_{\text{Min}}} + t_{\text{SRD}}$, the enable output is deasserted (see [Figure 21](#)).

Hardware reset or power-down while system not responding

If the system is not responding and the system hangs, the $\overline{\text{PB}}$ and $\overline{\text{SR}}$ push-button can be pressed simultaneously longer than $t_{\text{DEBOUNCE}} + t_{\text{INT_Min}} + t_{\text{SRD}}$, and then

- a) either the reset output $\overline{\text{RST}}$ is asserted for t_{REC} and the processor is reset (valid only for the device with option “ $\overline{\text{RST}}$ asserted by long push”) – see [Figure 18](#)
- b) or the power is disabled by EN or $\overline{\text{EN}}$ signal (valid only for the device with option “EN deasserted by long push”) – see [Figure 19](#)

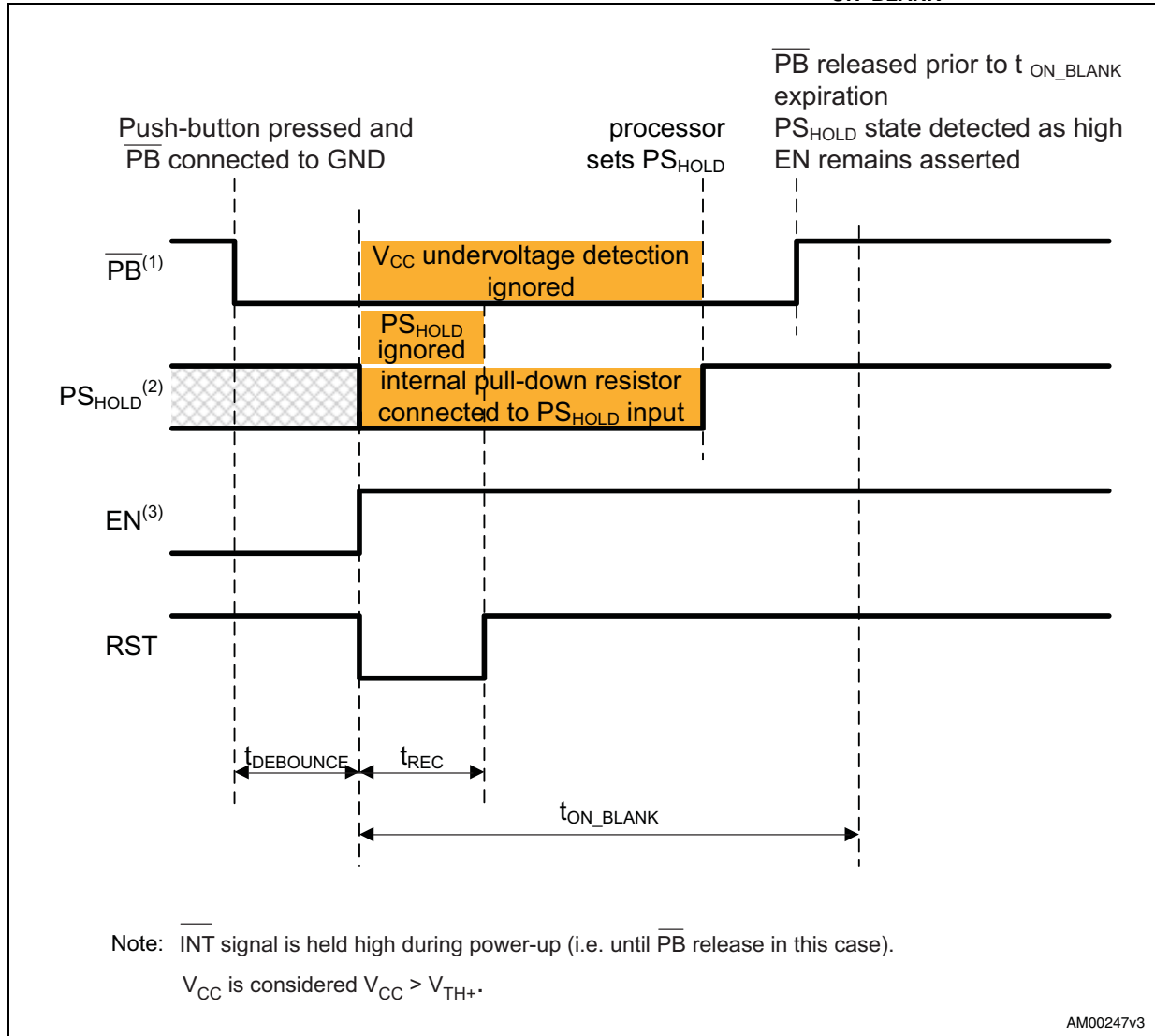
The t_{SRD} is set by the external capacitor connected to the C_{SRD} pin. $\overline{\text{SR}}$ input is monitored for falling edge after power-up and must not be grounded permanently.

Standby

If the enable output is deasserted (i.e. EN is low or $\overline{\text{EN}}$ is high), the STM660x device enters standby mode with low current consumption (see [Table 5](#)). In standby mode $\overline{\text{PB}}$ input is only monitored for the falling edge. The external 1.5 V voltage reference is also disabled in standby mode.

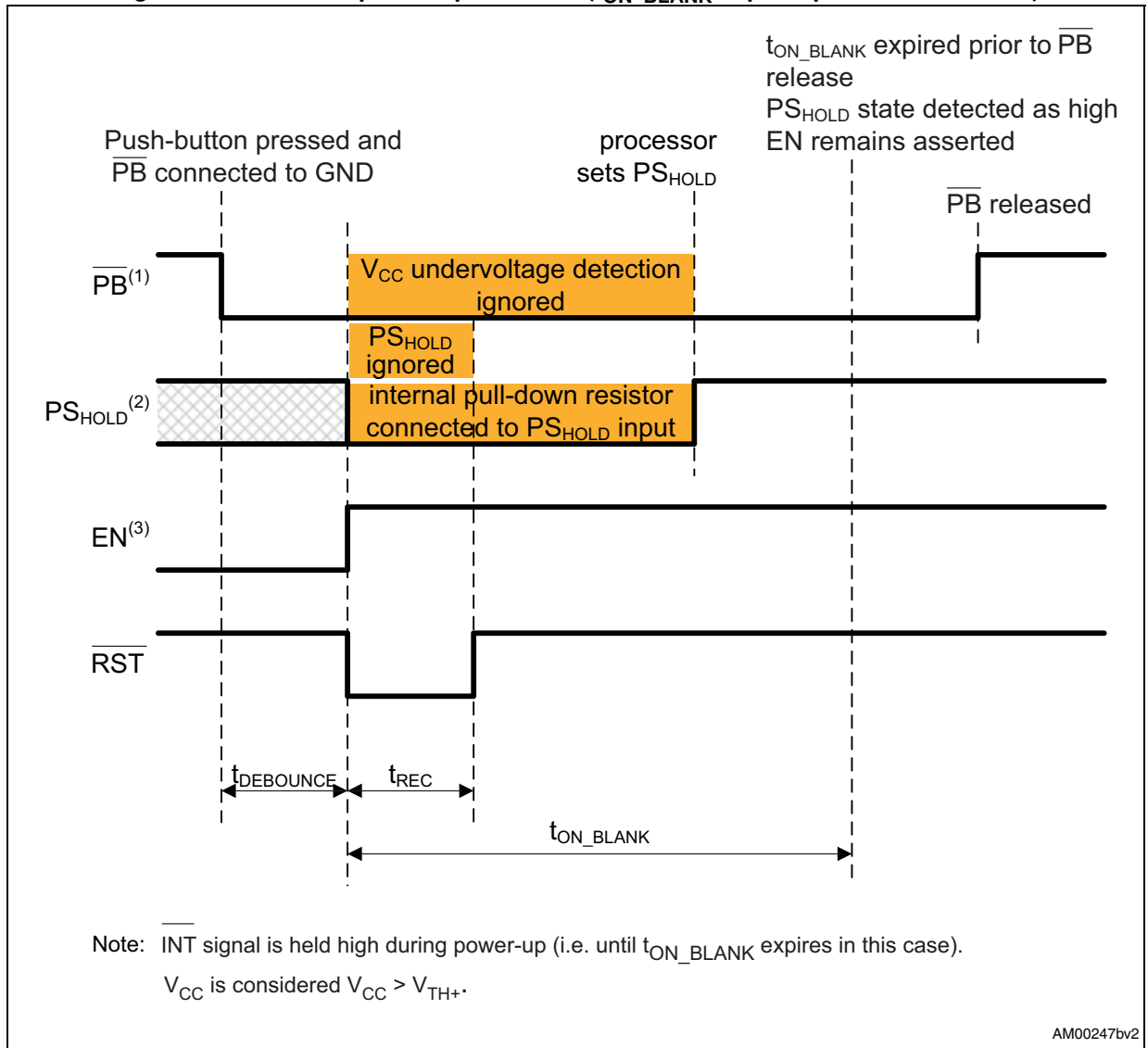
4 Waveforms

Figure 7. Successful power-up on SRC0 ($\overline{\text{PB}}$ released prior to $t_{\text{ON_BLANK}}$ expiration)



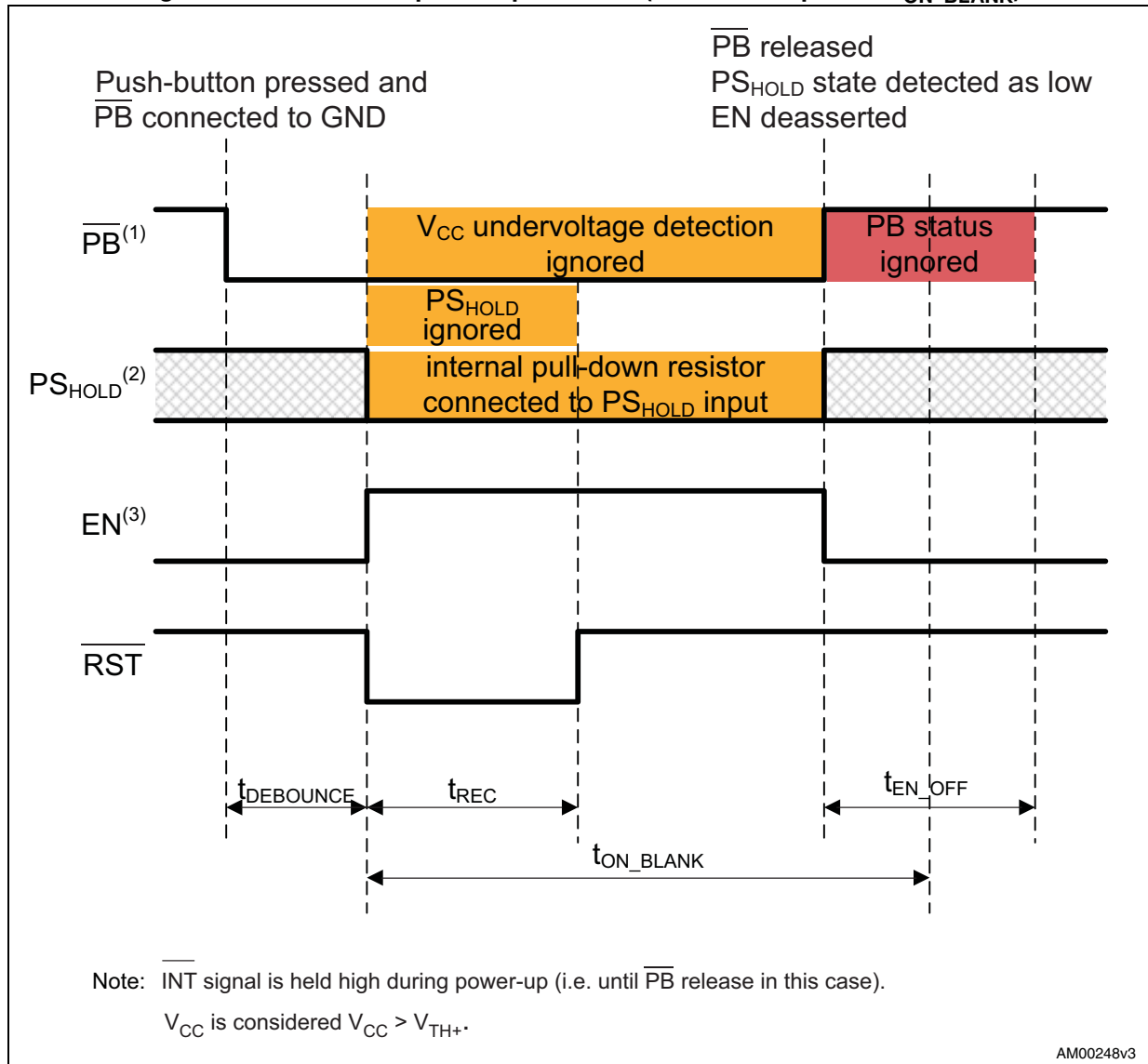
1. $\overline{\text{PB}}$ detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. EN signal is high even after $\overline{\text{PB}}$ release, because processor sets PS_{HOLD} signal high before $\overline{\text{PB}}$ is released.

Figure 8. Successful power-up on SRC0 (t_{ON_BLANK} expires prior to \overline{PB} release)



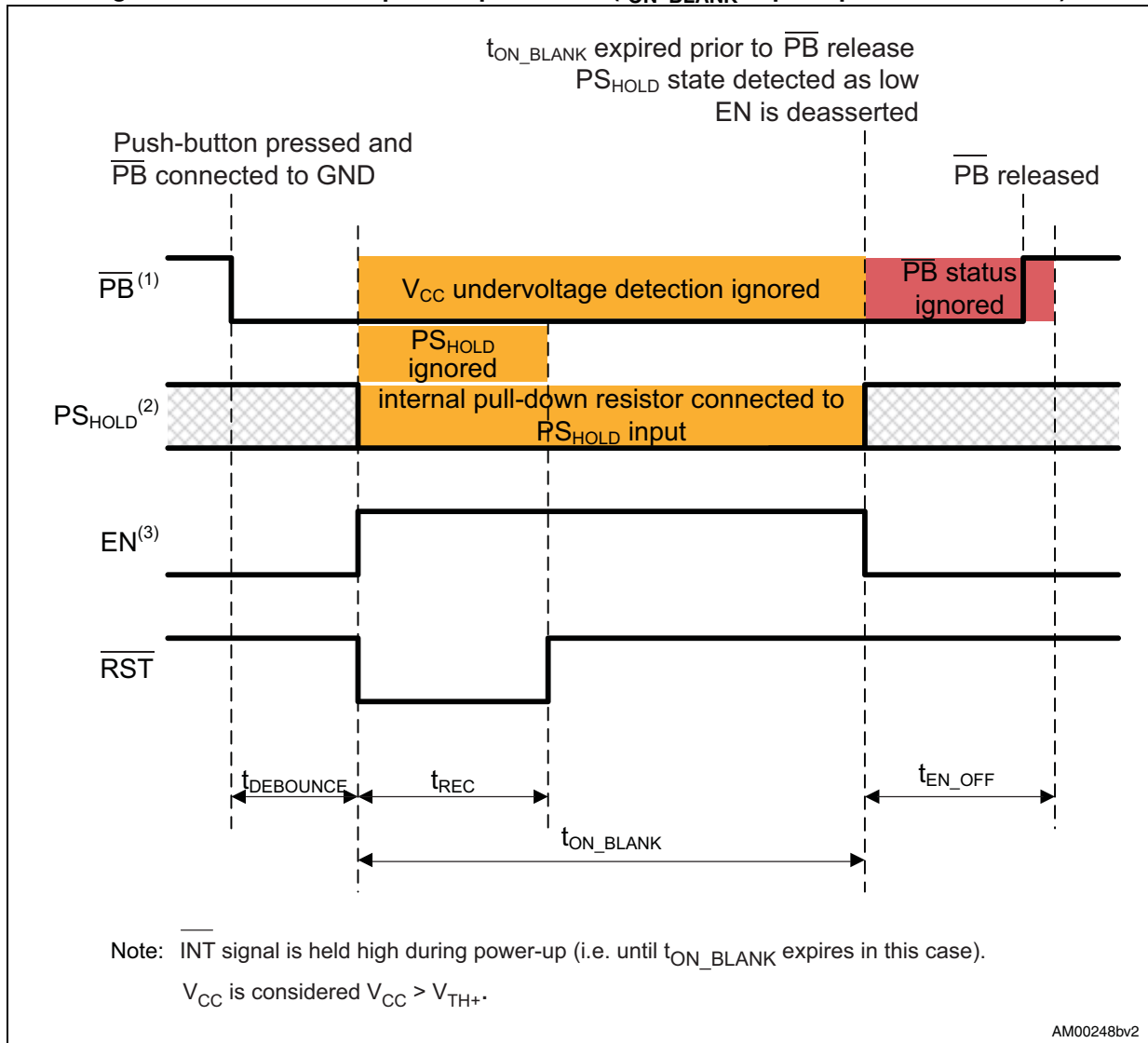
1. \overline{PB} detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. t_{ON_BLANK} expires prior to \overline{PB} release so PS_{HOLD} is checked at its expiration.

Figure 9. Unsuccessful power-up on SRC0 ($\overline{\text{PB}}$ released prior to $t_{\text{ON_BLANK}}$)



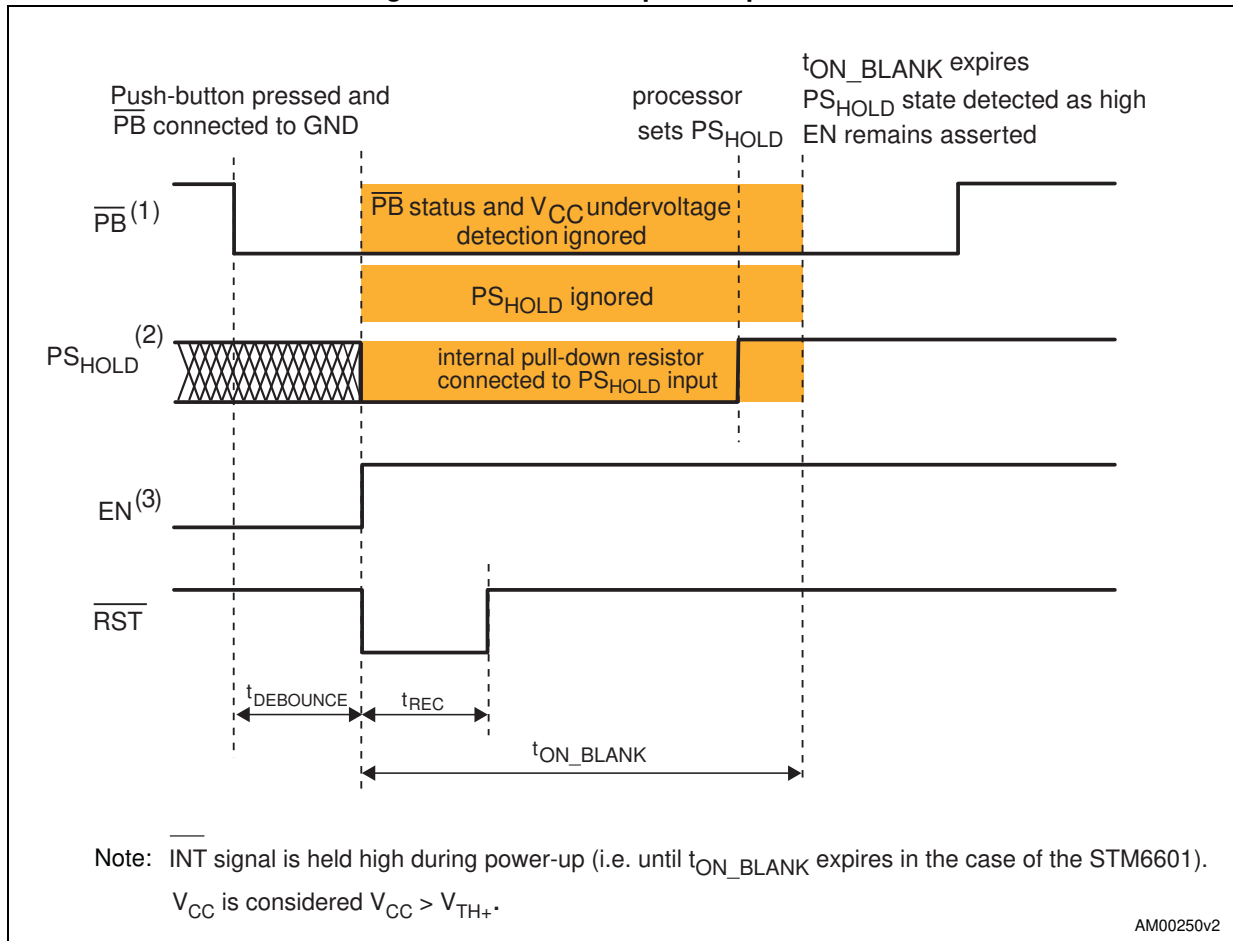
1. $\overline{\text{PB}}$ detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. EN signal goes low with $\overline{\text{PB}}$ release, because processor did not force PS_{HOLD} signal high.

Figure 10. Unsuccessful power-up on SRC0 (t_{ON_BLANK} expires prior to \overline{PB} release)



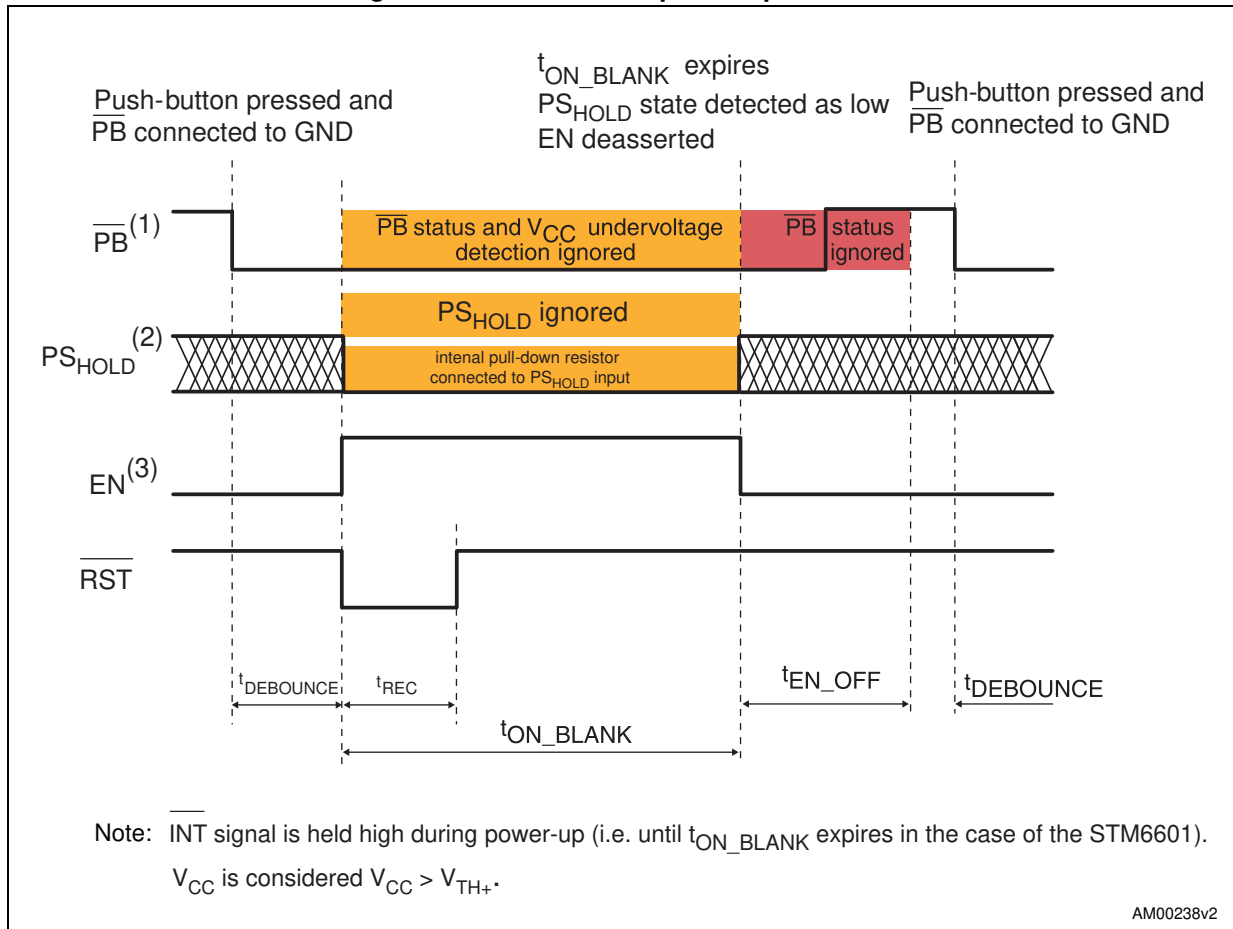
1. \overline{PB} detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. t_{ON_BLANK} expires prior to \overline{PB} release so PS_{HOLD} is checked at its expiration.

Figure 11. Successful power-up on SRC0



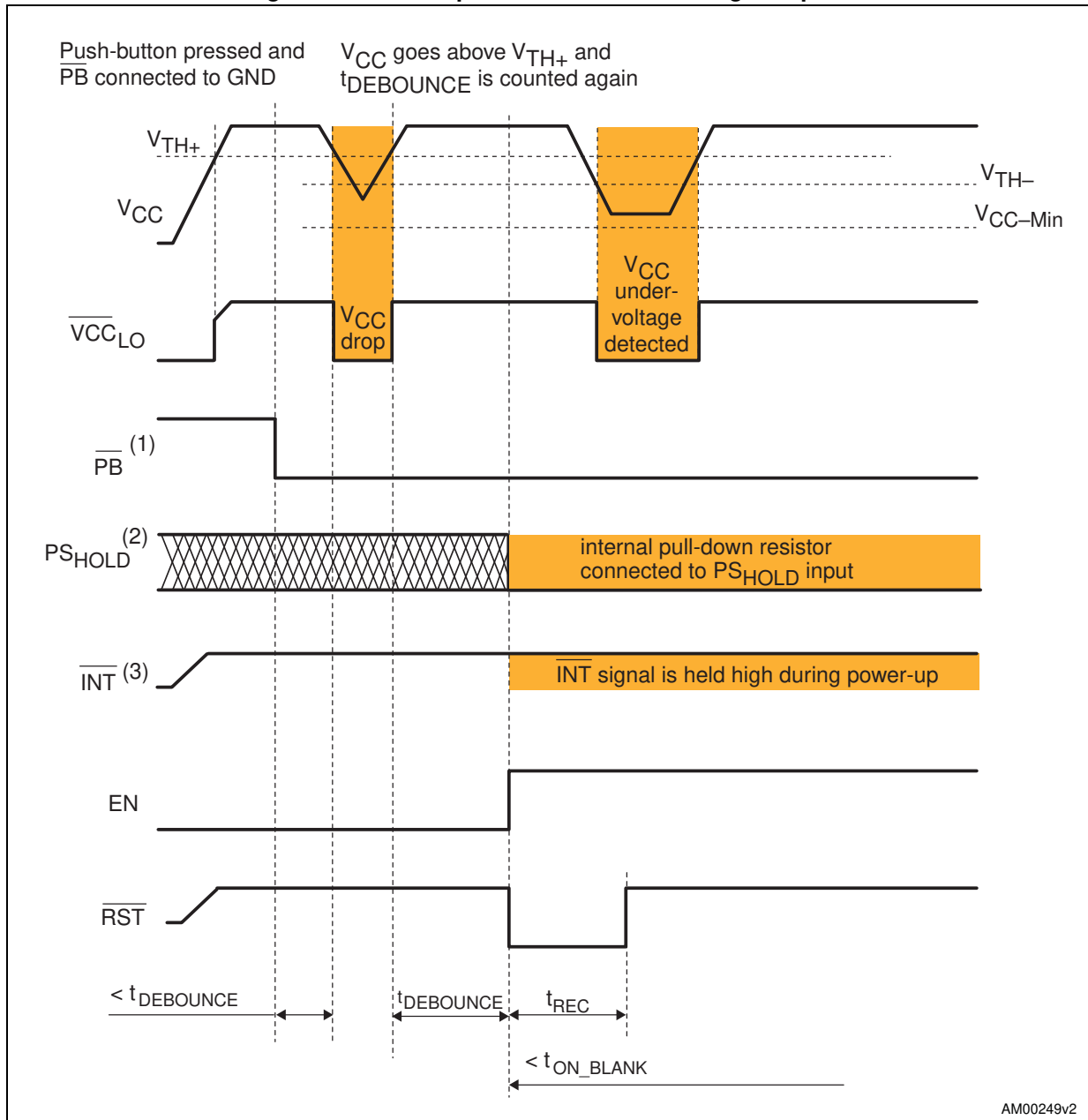
1. \overline{PB} detection on falling edge.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. PS_{HOLD} signal is ignored during t_{ON_BLANK} . When t_{ON_BLANK} expires, the level of the PS_{HOLD} signal is high therefore the EN signal remains asserted.

Figure 12. Unsuccessful power-up on SRC0



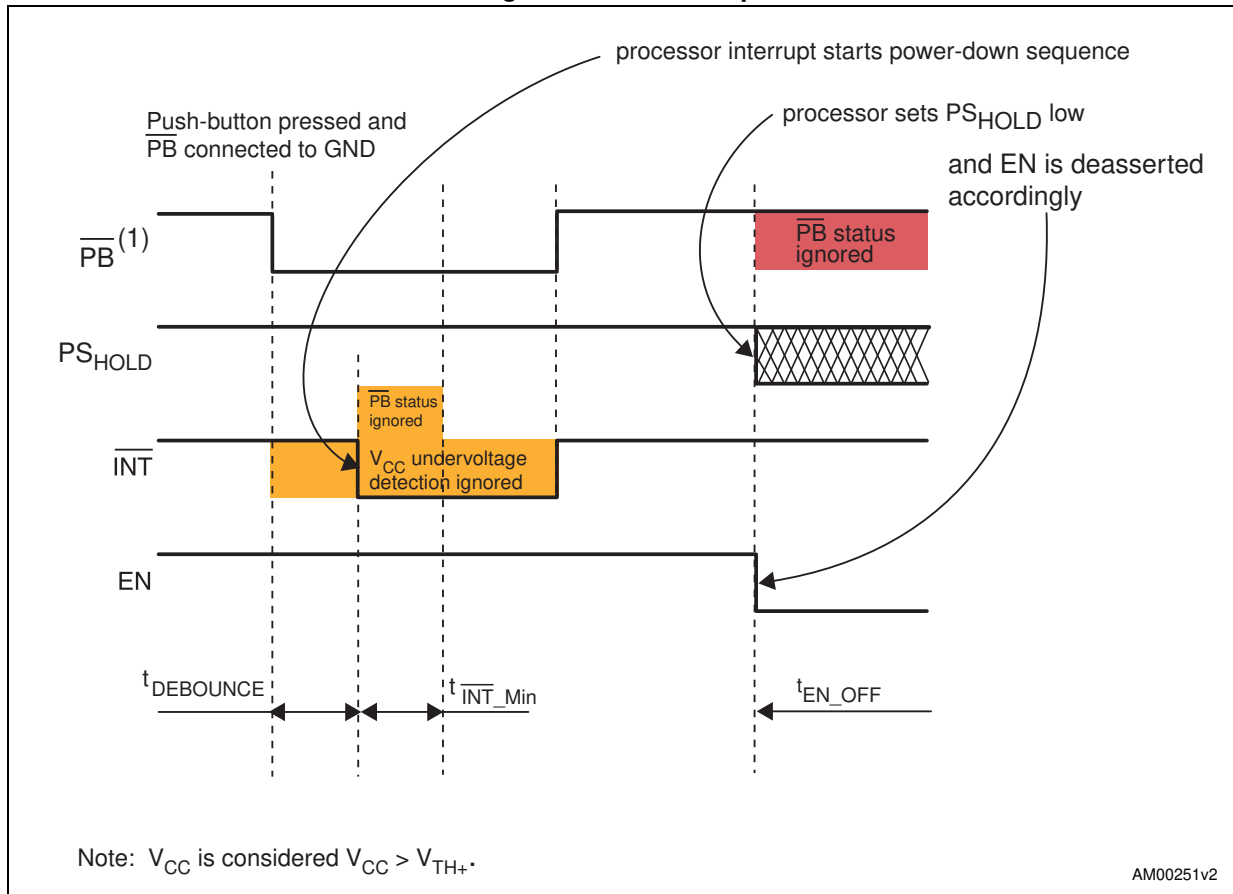
1. \overline{PB} detection on falling edge.
2. Internal pull-down resistor 300 kΩ is connected to PS_HOLD input during power-up.
3. PS_HOLD signal is ignored during t_{ON_BLANK} . When t_{ON_BLANK} expires, the level of the PS_HOLD signal is not high therefore the EN signal goes low. Even releasing the PB button after the t_{ON_BLANK} will not prevent this.

Figure 13. Power-up on STM660x with voltage dropout



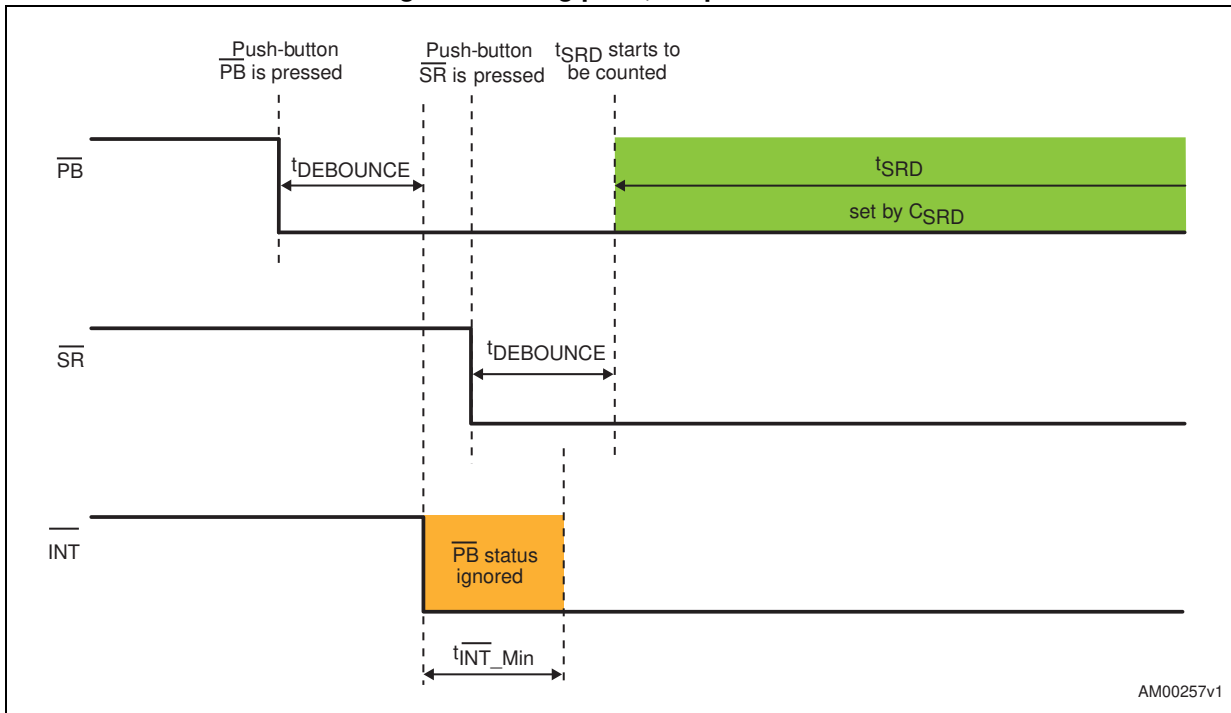
1. $\overline{\text{PB}}$ detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. $\overline{\text{INT}}$ signal is held high during power-up.

Figure 14. $\overline{\text{PB}}$ interrupt



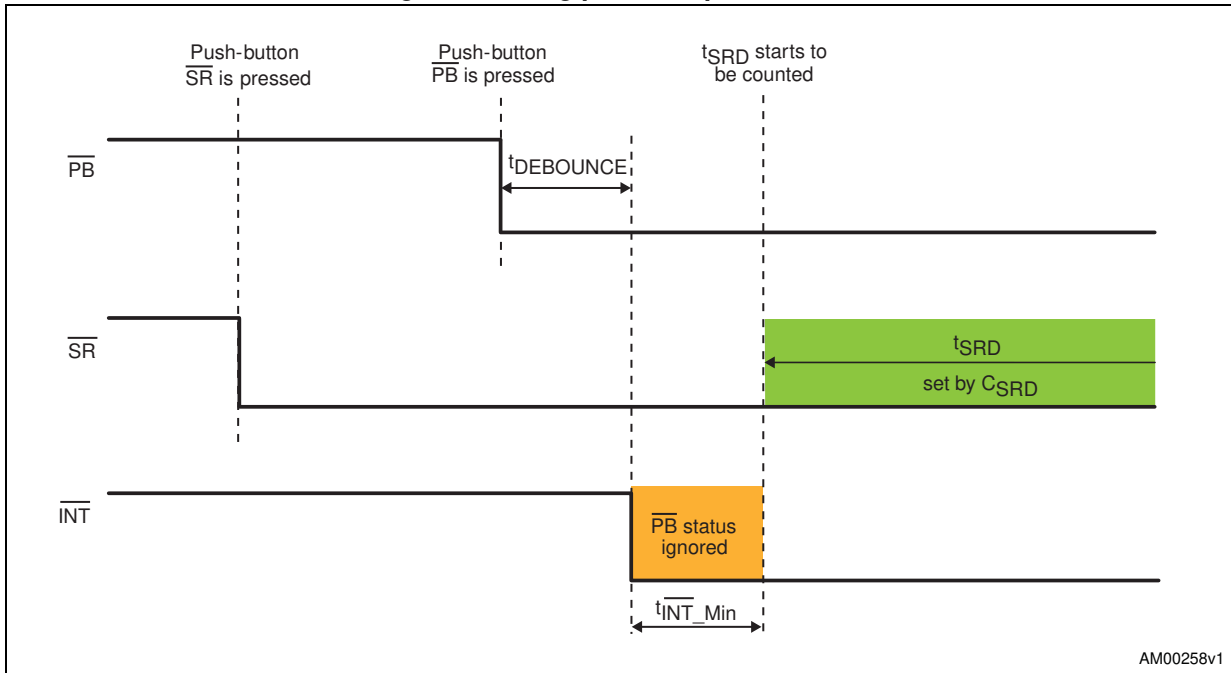
1. $\overline{\text{PB}}$ detection on falling edge.

Figure 15. Long push, $\overline{\text{PB}}$ pressed first



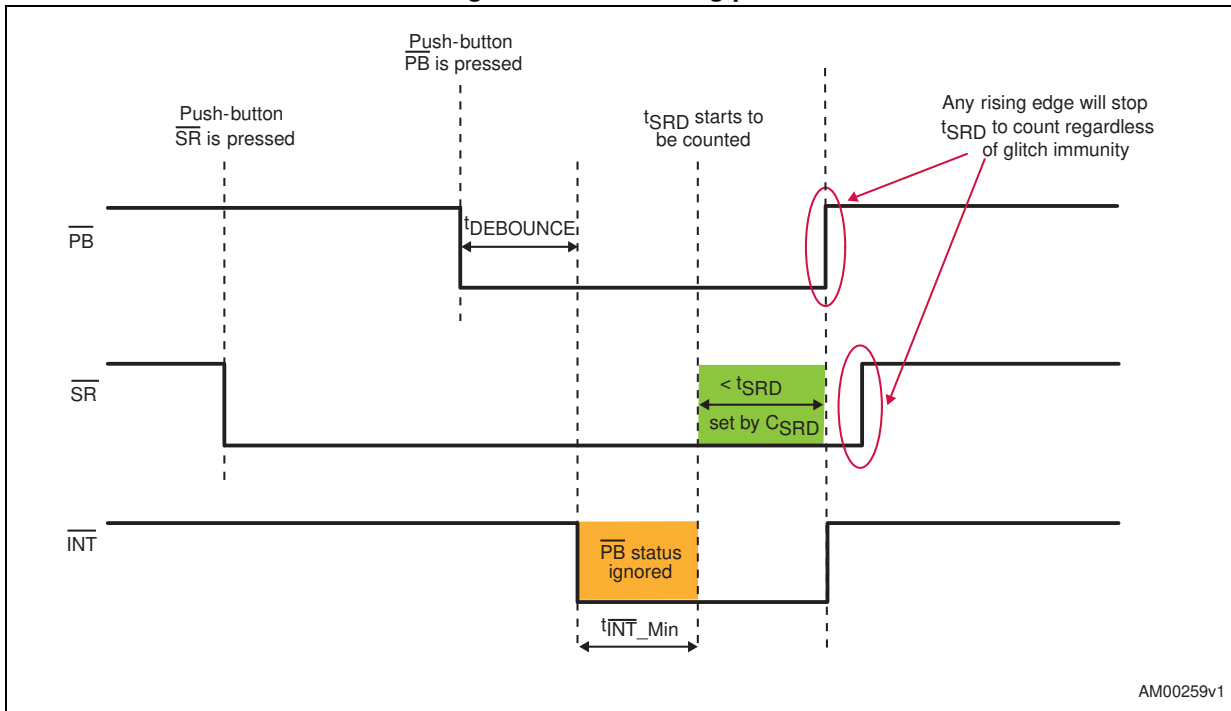
AM00257v1

Figure 16. Long push, $\overline{\text{SR}}$ pressed first



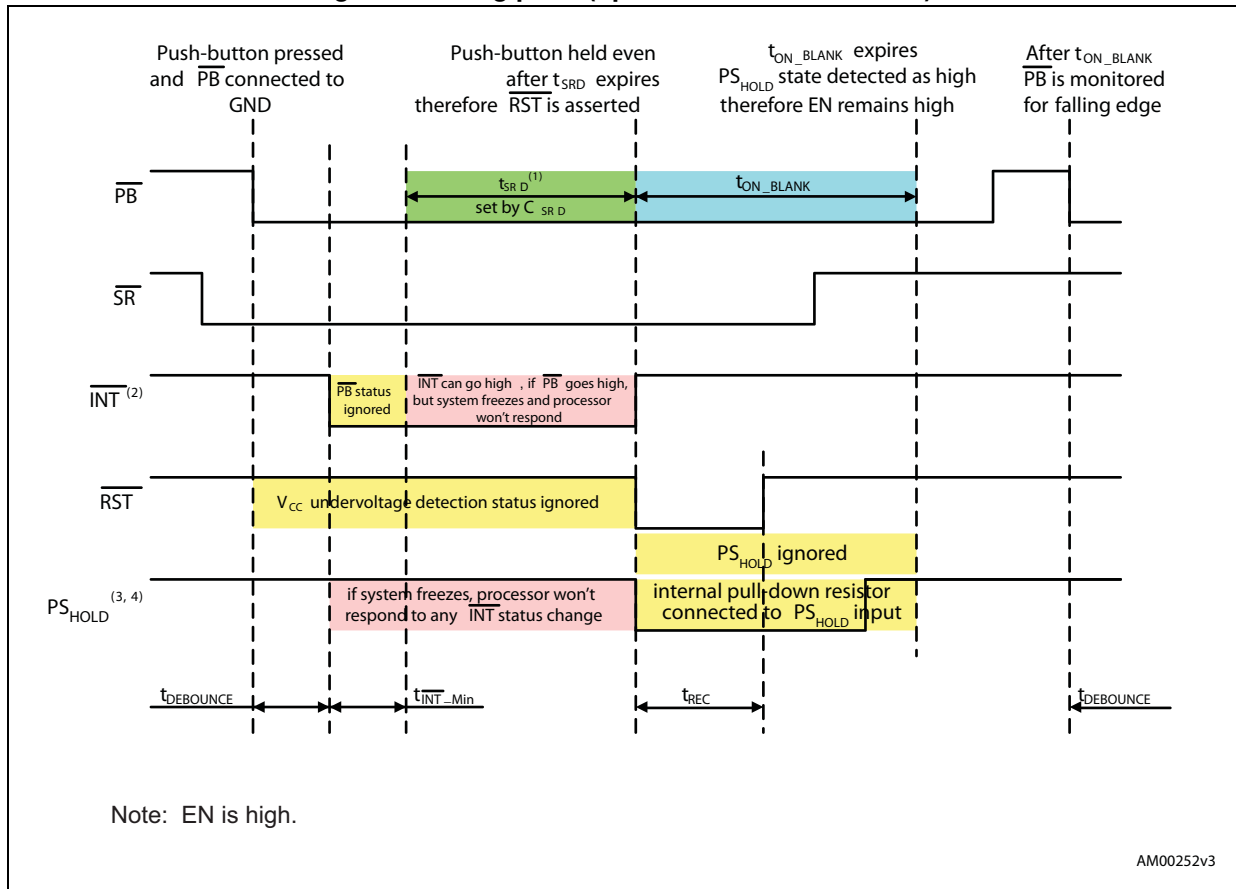
AM00258v1

Figure 17. Invalid long push



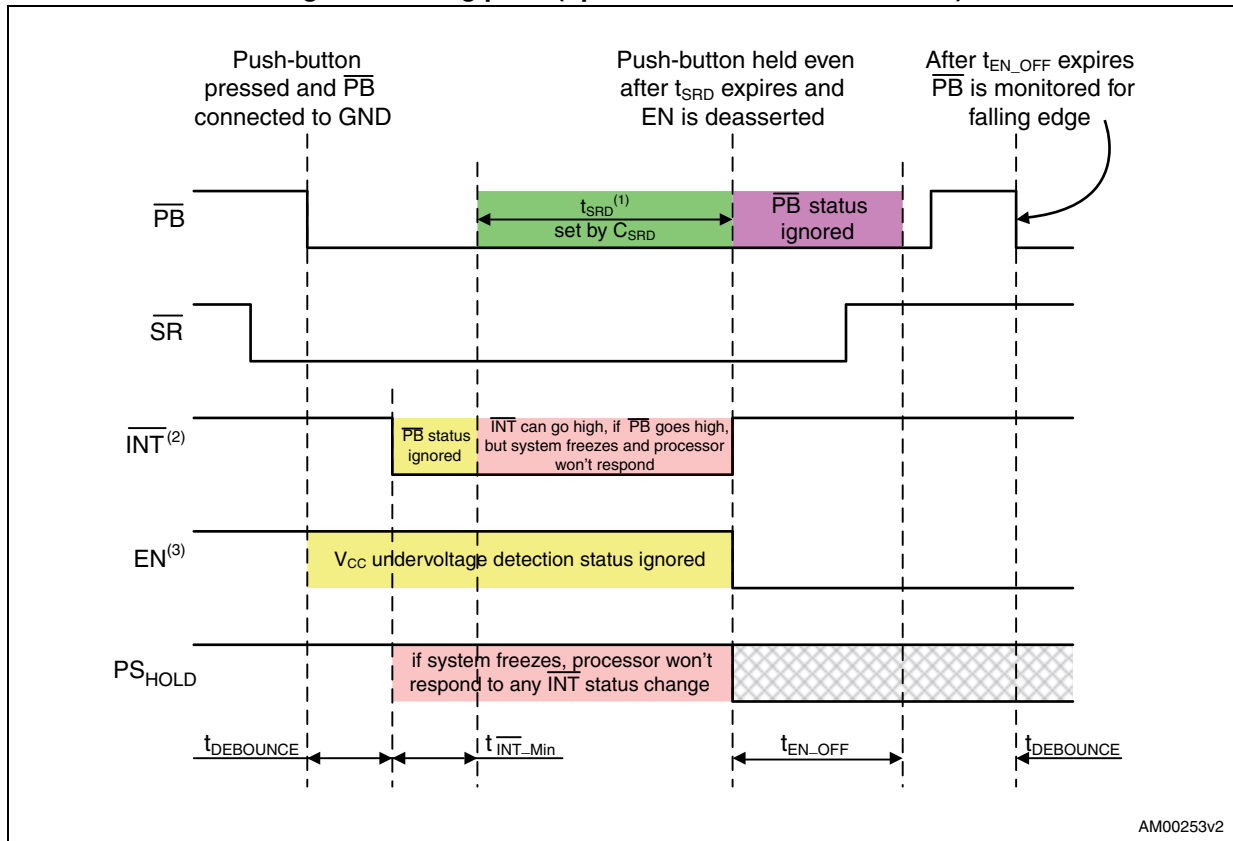
AM00259v1

Figure 18. Long push (option with $\overline{\text{RST}}$ assertion)



1. $t_{\text{SR D}}$ period is set by external capacitor $C_{\text{SR D}}$.
2. PB ignored during $t_{\text{INT_Min}}$.
3. PS_{HOLD} signal is ignored during $t_{\text{ON_BLANK}}$. Its level is checked after $t_{\text{ON_BLANK}}$ expires and if it is high the EN signal remains asserted, otherwise EN goes low.
4. Internal pull-down resistor $300\text{ k}\Omega$ is connected to PS_{HOLD} input during startup when device is reset.

Figure 19. Long push (option with enable deassertion)



1. t_{SRD} period is set by external capacitor C_{SRD} .
2. \overline{PB} ignored during t_{INT_Min} .
3. After t_{SRD} expires EN is forced low.